

# Reducing the efficiency–stability–cost gap of organic photovoltaics with highly efficient and stable small molecule acceptor ternary solar cells

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**Technological deployment of organic photovoltaic modules requires improvements in device light-conversion efficiency and stability while keeping material costs low. Here we demonstrate highly efficient and stable solar cells using a ternary approach, wherein two non-fullerene acceptors are combined with both a scalable and affordable donor polymer, poly(3-hexylthiophene) (P3HT), and a high-efficiency, low-bandgap polymer in a single-layer bulk-heterojunction device. The addition of a strongly absorbing small molecule acceptor into a P3HT-based non-fullerene blend increases the device efficiency up to  $7.7 \pm 0.1\%$  without any solvent additives. The improvement is assigned to changes in microstructure that reduce charge recombination and increase the photovoltage, and to improved light harvesting across the visible region. The stability of P3HT-based devices in ambient conditions is also significantly improved relative to polymer:fullerene devices. Combined with a low-bandgap donor polymer (PBDTTT-EFT, also known as PCE10), the two mixed acceptors also lead to solar cells with  $11.0 \pm 0.4\%$  efficiency and a high open-circuit voltage of  $1.03 \pm 0.01$  V.**

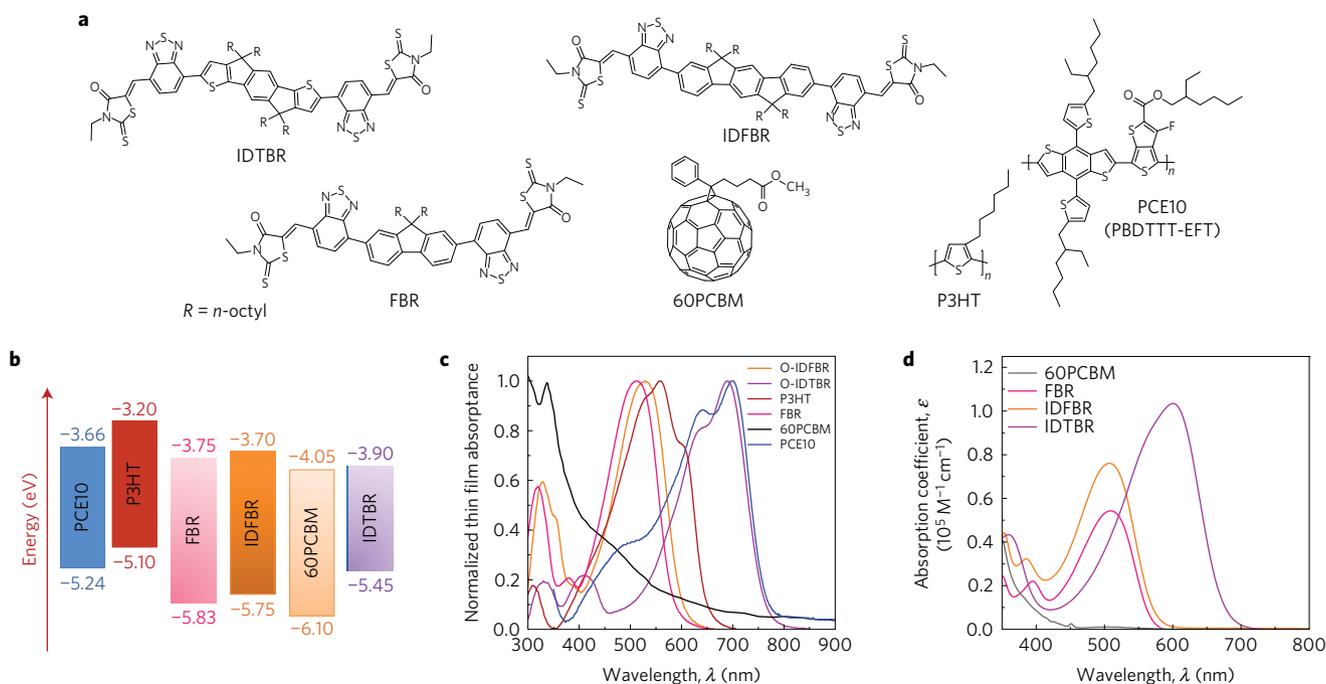
At present, the materials used in organic photovoltaics (OPV) are dominated by fullerene acceptors in combination with low-bandgap donor polymers which typically require complex and multi-step syntheses<sup>1–5</sup>. However, the commercialization of OPV requires the availability of inexpensive materials in large quantities, such as poly(3-hexylthiophene) (P3HT). P3HT is readily scalable via flow or micro-reactor synthesis, even using ‘green’ solvents, whilst retaining a high degree of control over molecular weight and regio-regularity<sup>6</sup>. The P3HT:60PCBM blend exhibits one of the most robust microstructures within OPV<sup>7–9</sup>. However, it has a limited open-circuit voltage ( $V_{oc}$ ) and short-circuit current ( $J_{sc}$ ) in photovoltaic devices<sup>10</sup>. We have recently shown that solar cells using an alternative small molecule non-fullerene acceptor (NFA), IDTBR, when mixed with P3HT, can achieve power conversion efficiencies of up to 6.4% (ref. 11). These results have revived interest in the use of P3HT for high-performance devices and non-fullerene acceptors<sup>12–18</sup>. The combination of stability, cost and performance for P3HT:NFA devices make them a compelling choice for commercialization of OPV compared to devices using fullerenes, for which the high costs and energy involved are prohibitive for large-scale production.

Recently, multi-component heterojunctions (ternary or more) have emerged as a promising strategy to overcome the power conversion efficiency (PCE) bottleneck associated with binary

bulk-heterojunction (BHJ) solar cells<sup>3,4,19–24</sup>. However, simultaneous increase in the  $V_{oc}$ ,  $J_{sc}$  and fill factor (FF) is a challenge in the ternary approach because of the trade-off between photocurrent and voltage<sup>23,25,26</sup>. Reports show ternary blends using fullerene acceptors, where the  $V_{oc}$  is increased using a second acceptor ( $A_2$ ) with a higher electron affinity (EA) than  $A_1$  (refs 23,27–29); however, very few examples of two-acceptor ternary blend devices could surpass the overall efficiency of their respective binary blends<sup>24,30,31</sup>. Therefore, the majority of studies on ternary solar cells have focused on multi-polymer donor:acceptor blends<sup>19,23,27–29</sup>. However, the mixing of two polymers is more complicated due to both a lack of entropic driving force for mixing, and the potential for strong intermolecular attractions between polymer chains<sup>32</sup>. Therefore, a ternary approach, wherein small molecule acceptors are mixed in a donor:multi-acceptor blend (D: $A_1$ : $A_2$ , where D is the donor polymer,  $A_1$  is the primary acceptor and  $A_2$  is a second acceptor), has the potential to offer morphological advantages. Small molecule NFAs have already reached >10% PCEs in binary BHJ devices with low-bandgap donor polymers<sup>33</sup>; however, their potential in multi-component junctions has not yet been explored.

Here, we demonstrate highly efficient solar cells by both combining P3HT with two NFAs in a ternary blend, as well as extending this approach to utilize a high-efficiency, low-bandgap polymer PCE10, in place of P3HT. Through optimizing the acceptor

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**Figure 1 | Chemical structures, energy levels and optical properties of materials used in this study. a**, Chemical structures of the acceptor molecules and the donor polymers used in this study. **b**, Energy level diagram measured from thin films using cyclic voltammetry. **c**, Normalized thin-film absorptions of neat donor and acceptor materials used in this study. **d**, Absorption coefficients of 60PCBM, FBR, IDFBR and IDTBR solutions in chloroform solution ( $1 \times 10^{-5}$  M).

phase loading ratio in a D:A<sub>1</sub>:A<sub>2</sub> blend, and molecular packing with respect to the binary blend, we demonstrate a concurrent improvement in  $J_{sc}$ ,  $V_{oc}$  and FF, resulting in a PCE of  $7.7 \pm 0.1\%$  for P3HT cells. These improvements motivated using the D:A<sub>1</sub>:A<sub>2</sub> concept with a high-performing PCE10, which yields  $11.0 \pm 0.4\%$  efficiency in single-layer ternary devices. Although these high-efficiency devices outperform the P3HT devices, the ease of synthesis of the NFAs and P3HT blend has the potential to greatly benefit the effective cost of solar energy production.

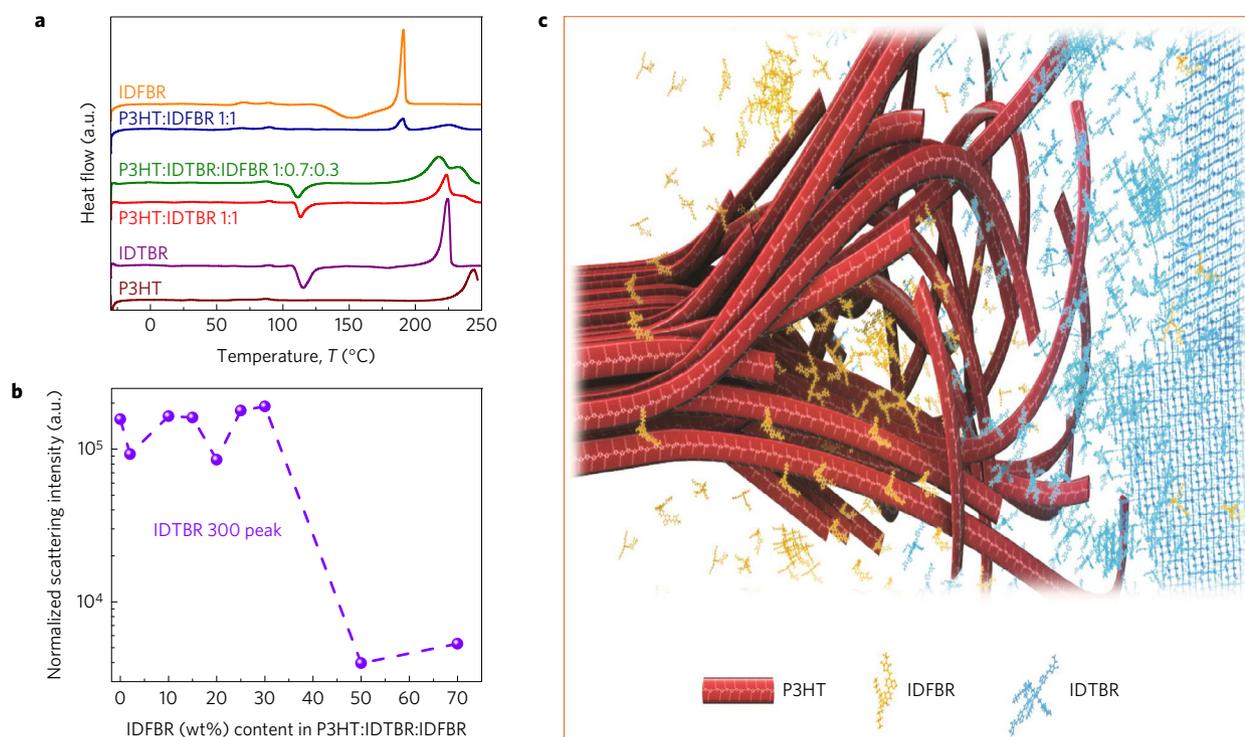
### Characterization of neat materials and blends

Previously, we have shown that a NFA containing an indenodithiophene core flanked with benzothiadiazole and rhodanine groups, named IDTBR (A<sub>1</sub>), can deliver 6.4% PCE in a solar cell device when combined with P3HT (D), which is the highest P3HT:NFA performance reported<sup>11</sup>. To further boost the efficiency of P3HT devices, we include three different NFAs as third components (A<sub>2</sub>) into a P3HT:IDTBR blend (Fig. 1). In this instance, A<sub>2</sub> is either the fluorene-core analogue of IDTBR (FBR)<sup>12</sup>, a new indenofluorene analogue of IDTBR called IDFBR (see Supplementary Information)<sup>12,34</sup>, or 60PCBM, which is the most investigated acceptor molecule used in combination with P3HT in BHJ solar cells. Unlike 60PCBM, both FBR and IDFBR have linear, donor–acceptor molecular structures similar to IDTBR, including having flanking rhodanine and benzothiadiazole units<sup>11,12</sup>. From the energy level diagram shown in Fig. 1b, FBR and IDFBR have a 0.1–0.2 eV lower EA compared to IDTBR as measured by thin-film cyclic voltammetry (CV). Ultraviolet–visible (UV–Vis) absorption spectra of solutions and thin films determined the spectral range of each material in the visible region (Fig. 1c). Relative to 60PCBM, the absorption spectra of FBR and IDFBR show significantly stronger absorption, with absorption maxima ( $\lambda_{max}$ ) at around 510 nm and 530 nm, respectively. Furthermore, both FBR and IDFBR have complementary absorption spectra to that of IDTBR, which has a  $\lambda_{max}$  at 690 nm and absorption that extends into the near-infrared region. The non-fullerene acceptors have extinction coefficients at

their absorption maxima that are an order of magnitude greater than 60PCBM in the visible (Fig. 1d), which should assist increased photon harvesting in solar cells (Supplementary Table 1). The UV–Vis absorption spectra of binary and ternary blend films show interesting phenomena upon annealing at 130 °C for 10 min. The absorption spectrum of the P3HT:IDTBR film exhibits a significant red shift of about 40 nm in the low-energy peak upon annealing, which is ascribed to a high degree of aggregation of IDTBR in the film. However, there is no observed shift upon annealing of any of the ternary P3HT:IDTBR:A<sub>2</sub> blends, indicating that the aggregation of IDTBR is suppressed in the ternary blend (Supplementary Fig. 1b).

### Morphology picture of the ternary blends

To elucidate the role of the A<sub>2</sub> in the ternary blends we carried out differential scanning calorimetry (DSC) and *in situ* grazing incidence wide angle X-ray scattering (GIWAXS) measurements during spin coating of P3HT:IDTBR:A<sub>2</sub> ternary films from chlorobenzene solution (higher-resolution diffraction patterns were collected *ex situ*, as discussed below). The relative degree of crystallinity of the donor for each ternary blend was calculated by fitting the GIWAXS spectra (Supplementary Fig. 2a)<sup>35–37</sup>. *In situ* GIWAXS measurements suggest that, in all ternary blends, P3HT crystallization appears at the very end of solvent evaporation, as characterized by a sharp increase in scattering intensity associated with P3HT lamellar stacking and a sharp decrease in solvent scattering intensity (Supplementary Fig. 2a,b)<sup>35,38</sup>. The unperturbed P3HT crystallization can be understood by the fact that P3HT reaches supersaturation in solution and starts to crystallize earlier than all of the other components, which is further supported by *in situ* UV–Vis absorption measurements performed during spin coating (Supplementary Fig. 3)<sup>38</sup>. GIWAXS measurements performed on as-cast and thermally annealed (130 °C) films are also summarized in Supplementary Fig. 2c and d, respectively. The crystalline correlation length (CCL) and the relative crystallinity of the P3HT phase for each of the



**Figure 2 | Microstructural analysis of P3HT:IDTBR:IDFBR ternary blend.** **a**, The first DSC heating profiles of individual P3HT, IDTBR and IDFBR along with binary P3HT:IDTBR, P3HT:IDFBR and ternary P3HT:IDTBR:IDFBR blends. **b**, 2D GIWAXS profile for the P3HT:IDTBR:IDFBR blend with varying IDFBR loading, focusing on the characteristic crystallinity peak of IDTBR (300). **c**, Visual illustration of the binary P3HT:IDTBR blend with IDFBR presence, wherein the crystallinity of both P3HT and IDTBR is preserved.

ternary blends have been calculated in Supplementary Table 2 (ref. 39). The as-cast P3HT:IDTBR:60PCBM blend exhibits the lowest P3HT crystallinity and CCL (corresponding to the smallest crystallite size). P3HT:IDTBR:IDFBR exhibits the highest relative crystallinity amongst ternary films, indicating more pronounced polymer:small molecule phase separation for both the as-cast and annealed films.

DSC profiles of P3HT, IDTBR and IDFBR in the neat, binary and the best performing P3HT:IDTBR:IDFBR ternary blend are presented in Fig. 2a. The heat flow profiles reveal that both the IDFBR and IDTBR binary blends with P3HT exhibit broad endothermic transitions at temperatures above  $200^{\circ}\text{C}$ , attributed to a P3HT crystalline phase melt. In comparison to the pristine P3HT, the melting transition of P3HT is broadened and suppressed in all blends, most significantly in the P3HT:IDFBR blend (factor of 5). In the P3HT:IDTBR blend, the P3HT melting endotherm is prominent, although its peak has still been slightly depressed and broadened, and there is a minimal reduction in melting enthalpy. In the ternary blend film, the P3HT crystalline phase still persists, with a broad melt endotherm. The comparison of the binaries indicates that both of the small molecule species can diffuse into the P3HT phase, with IDFBR doing so to a greater extent, leading to more extensive disorder in the polymer, in agreement with *in situ* GIWAXS observations of P3HT crystallization in such blends (Supplementary Fig. 2). The IDTBR crystalline transition in the ternary blend exhibits a melting point depression and lower enthalpy in comparison to the IDTBR binary film, indicating that the IDFBR has been able to also diffuse into the IDTBR phase. No evidence of any IDFBR thermal transitions is present in the ternary. The cooling scan (Supplementary Fig. 4a) shows a strongly super-cooled crystallization of P3HT, but no small-molecule crystallization. The ternary film, therefore, can be described as having three partially miscible components, comprising a crystalline P3HT phase, which also hosts a molecular dispersion of IDFBR molecules, as well

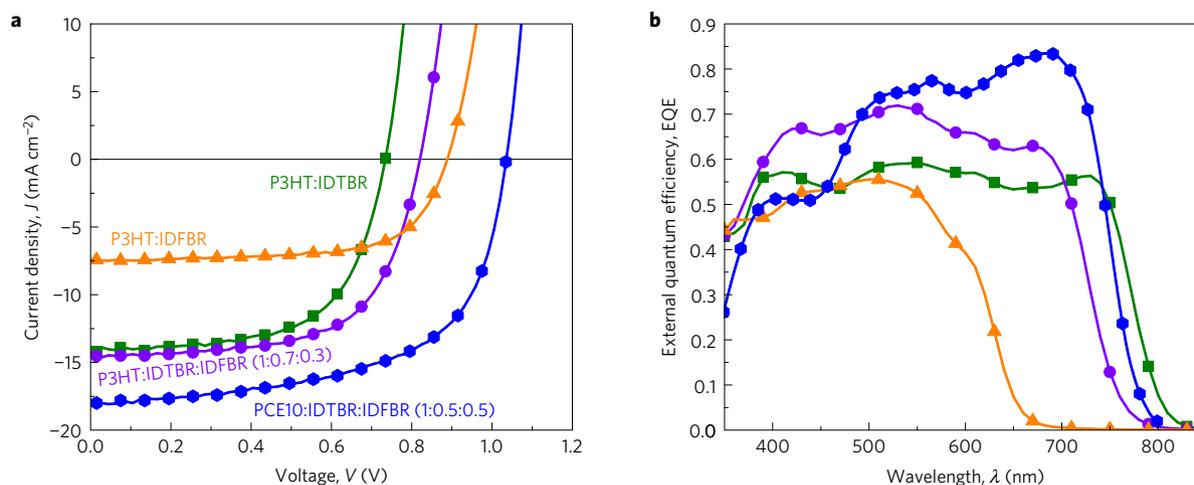
as an IDTBR-rich crystalline phase that also contains IDFBR. High-resolution two-dimensional (2D) GIWAXS patterns of a P3HT:IDTBR:IDFBR ternary blend were studied to understand the role of IDFBR in the optimized ternary blend (Supplementary Fig. 4b). The change in the intensity of the (300) peak of IDTBR ( $Q_z \approx 0.61 \text{ \AA}^{-1}$ ) is plotted in Fig. 2b as a function of  $A_1:A_2$  phase composition. The annealed P3HT:IDTBR (1:1) binary blend shows prominent crystallinity from both the polymer (reported above) and the acceptor (Supplementary Fig. 4b). The fact that the crystalline structure of P3HT is unperturbed by the presence of IDTBR is in agreement with the small shift of the P3HT melting point observed by DSC. The degree of P3HT crystallinity remains relatively constant upon addition of increasing amounts of IDFBR, whereas the fraction of IDTBR crystallites steadily decreases as IDTBR is replaced by IDFBR in the blend (Supplementary Fig. 4c). The optimized 1:0.7:0.3 P3HT:IDTBR:IDFBR ternary blend exhibits remnant crystallinity of the small molecule phase (illustrated schematically in Fig. 2c). Above 30% IDFBR addition, the intensity of the IDTBR crystalline peak drops sharply, essentially reducing to noise for all IDFBR compositions up to 70% (Supplementary Fig. 4d,e). Hence, it appears that IDFBR dissolves in the P3HT and, as its weight fraction is increased, it vitrifies the remaining IDTBR. This makes the acceptor phase a disordered solid solution of the two molecules, whereas the crystalline order of the polymer appears to be mostly unperturbed.

### Photovoltaic device characterization

The photovoltaic parameters for D:A<sub>1</sub> and D:A<sub>1</sub>:A<sub>2</sub> devices are summarized in Table 1. Representative current density–voltage ( $J$ – $V$ ) characteristics of binary P3HT:IDTBR and P3HT:IDFBR devices and ternary P3HT:IDTBR:IDFBR (1:0.7:0.3) and PCE10:IDTBR:IDFBR (1:0.5:0.5) devices under 1 sun illumination are shown in Fig. 3a. The P3HT:IDTBR device exhibits a  $J_{sc}$  and FF of  $13.9 \text{ mA cm}^{-2}$  and 0.60, respectively, and a  $V_{oc}$  of

**Table 1 | Photovoltaic parameters for binary and ternary blends.**

| Blend             | Blend ratio | $J_{sc}$ ( $\text{mA cm}^{-2}$ ) | $V_{oc}$ (V)    | FF              | PCE (%)        |
|-------------------|-------------|----------------------------------|-----------------|-----------------|----------------|
| P3HT:IDTBR        | 1:1         | $13.9 \pm 0.2$                   | $0.72 \pm 0.01$ | $0.60 \pm 0.03$ | $6.3 \pm 0.1$  |
| P3HT:IDTBR:IDFBR  | 1:0.7:0.3   | $14.4 \pm 0.3$                   | $0.82 \pm 0.01$ | $0.64 \pm 0.01$ | $7.7 \pm 0.1$  |
| P3HT:IDTBR:FBR    | 1:0.7:0.3   | $12.2 \pm 0.2$                   | $0.80 \pm 0.01$ | $0.62 \pm 0.01$ | $6.0 \pm 0.1$  |
| P3HT:IDTBR:60PCBM | 1:0.7:0.3   | $11.9 \pm 0.3$                   | $0.59 \pm 0.01$ | $0.51 \pm 0.02$ | $3.6 \pm 0.2$  |
| PCE10:IDTBR:IDFBR | 1:0.5:0.5   | $17.2 \pm 0.1$                   | $1.03 \pm 0.01$ | $0.6 \pm 0.01$  | $11.0 \pm 0.4$ |



**Figure 3 | Photovoltaic performances and EQE profiles of binary and ternary devices.** **a**, Current density–voltage ( $J$ – $V$ ) characteristics of binary and ternary devices under 1 sun illumination. The labels specify the donor:acceptor blends and ratios with P3HT and PCE10. **b**, EQE spectra of corresponding photovoltaic devices.

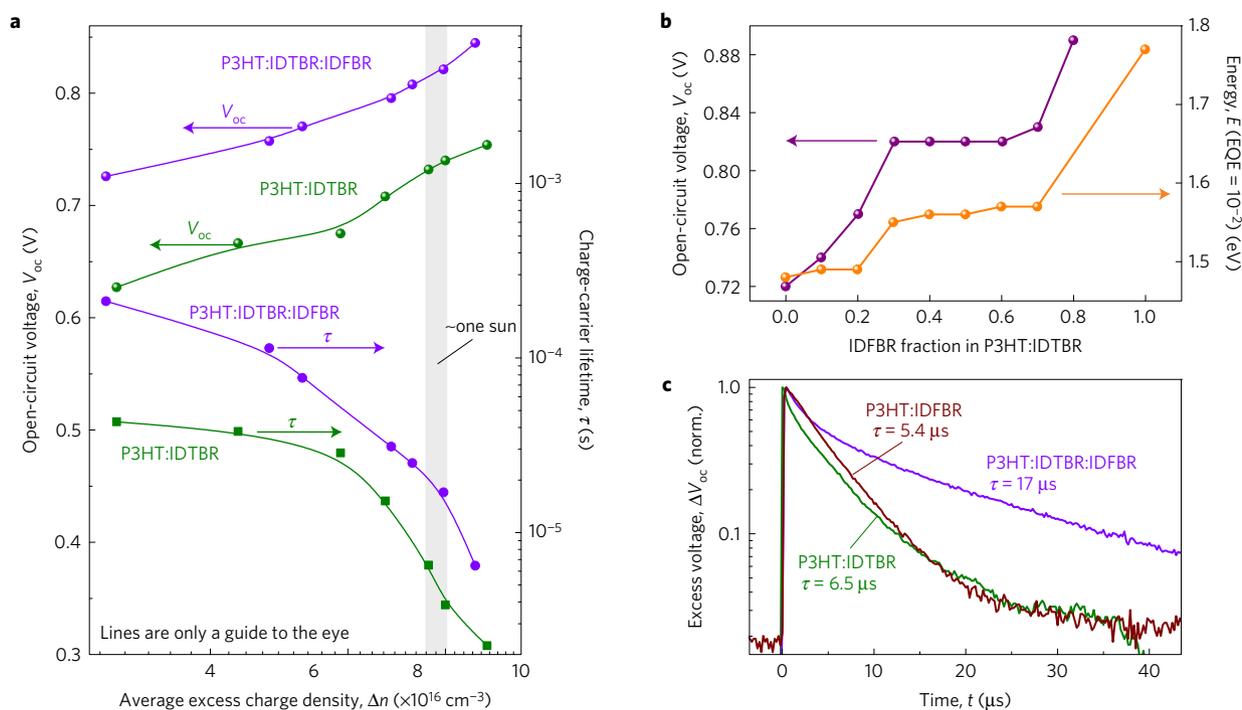
0.73 V which is relatively high for a P3HT-based solar cell ( $0.58$  V for P3HT:60PCBM)<sup>12</sup>, resulting in a PCE of 6.3% (Supplementary Table 3). The P3HT:IDFBR devices are optimized for an equal 1:1 D:A ratio in chlorobenzene, which gives remarkably high  $V_{oc}$  and FF values up to 0.88 V and 0.64, respectively, but a lower  $J_{sc}$ , with an overall efficiency of 4.5% (Supplementary Table 4). In comparison to binary blends, the addition of IDFBR as  $A_2$  in the P3HT ternary blend shows a significant improvement in the overall PCE to  $7.7 \pm 0.1\%$  (Fig. 3a). The best P3HT:IDTBR:IDFBR devices are achieved with a ratio of 1:0.7:0.3 (D:A<sub>1</sub>:A<sub>2</sub>), giving a  $J_{sc}$  of  $14.4 \text{ mA cm}^{-2}$ , FF of 0.64 and a  $V_{oc}$  of 0.82 V, which lies between those of the two binary devices. Further addition (up to 70%) of IDFBR resulted in  $V_{oc}$  values of 0.82 V, but a decrease in  $J_{sc}$ , which is mainly attributed to the reduced absorption at long wavelengths from IDTBR in the ternary blend (Supplementary Fig. 5). It is also noteworthy that P3HT:IDTBR:IDFBR devices can retain the high FF values of the binaries (0.64) with slightly lower  $V_{oc}$  and  $J_{sc}$  ( $0.78$  V and  $11.3 \text{ mA cm}^{-2}$ ) with an overall efficiency of 5.7% at thicknesses  $\sim 200$  nm (Supplementary Fig. 6a). Additionally, larger-area P3HT:IDTBR:IDFBR devices ( $\sim 1 \text{ cm}^2$ ) have also been demonstrated successfully with efficiencies as high as 6.5% with slightly lower FF (Supplementary Fig. 6b) (Supplementary Table 5). The substitution of IDFBR with either 60PCBM or FBR as  $A_2$  gave significantly inferior results compared to the P3HT:IDTBR:IDFBR device performance, which is further detailed in the Supplementary Information. PBDTTT-EFT (PCE10) has recently attracted attention in polymer:NFA solar cells due to its high efficiency with fullerene derivatives and its absorption in the low-energy region in the spectrum<sup>32</sup>. To validate that using two NFAs can yield state of the art photovoltaic performances, we used a low-bandgap polymer PCE10 with the same NFA acceptors in ternary solar cells. The un-optimized preliminary results showed that a PCE of  $11.0 \pm 0.4\%$  is achievable with a  $V_{oc}$  of 1.03 V, a

high  $J_{sc}$  of  $17.3 \text{ mA cm}^{-2}$  and a decent FF of 0.61 using a 1:0.5:0.5 PCE10:IDTBR:IDFBR ratio without the need for any processing additive or heat treatment (Table 1). These results showed that the potential of high-performance polymers such as PCE10 can be boosted with the A<sub>1</sub>:A<sub>2</sub> approach using NFAs.

External quantum efficiency (EQE) spectra of binary P3HT:IDTBR and P3HT:IDFBR devices and the best ternary P3HT:IDTBR:IDFBR (1:0.7:0.3) and PCE10:IDTBR:IDFBR (1:0.5:0.5) devices are shown in Fig. 3b. Relative to the maximum P3HT:IDTBR EQE of 55% ( $\lambda_{max}$  at 500 nm), the maximum EQE of the P3HT:IDTBR:IDFBR blend shows a substantial increase up to 70% in the 400–700 nm region, which explains the integrated photocurrent enhancement in the EQE for the P3HT:IDTBR:IDFBR device. The high photocurrent of the PCE10:IDTBR:IDFBR ternary cells is confirmed with EQE measurements where a photo-conversion  $>70\%$  is observed between 500–700 nm, reaching a maximum of 85% around 700 nm. The integrated photocurrent from the EQE spectrum of PCE10 ternary solar cells is consistent with the device  $J_{sc}$  values, confirming the very high photocurrent generation in the ternary devices. In all cases, the increased maximum EQE can be explained by improved light harvesting in the region where both polymer and A<sub>2</sub> absorb. However, the reduced EQE values beyond 500 nm, due to the low absorption strength of 60PCBM and, to some extent, of FBR, limits the  $J_{sc}$  from these ternary blends compared to the P3HT:IDTBR device (Supplementary Fig. 6c).

### Charge transport and recombination

To explain the simultaneous increase in  $V_{oc}$ ,  $J_{sc}$  and FF in the P3HT:IDTBR:IDFBR device compared to P3HT:IDTBR, we performed charge extraction, transient photovoltage (TPV) (at  $V_{oc}$ ) and space-charge-limited current (SCLC) measurements<sup>22,40</sup>. These measurements, in combination with sensitive EQE (where



**Figure 4 | Charge carrier dynamics of inverted P3HT:IDTBR and P3HT:IDTBR:IDFBR devices. a**,  $V_{oc}$  and recombination lifetime versus average excess charge density. **b**, Correlation between photon energies (at EQE =  $10^{-2}$ ) and  $V_{oc}$  of P3HT:IDTBR:IDFBR devices as a function of IDFBR content. **c**, TPV data for corresponding P3HT:IDTBR and P3HT:IDTBR:IDFBR blends at  $V_{oc}$  in response to a small additional light pulse.

a lock-in is used to increase the signal/noise ratio) and electroluminescence (EL)<sup>41</sup>, were utilized to explain the charge transport, recombination behaviour and the origin of the increased  $V_{oc}$  in the P3HT:IDTBR:IDFBR blend from different perspectives. Charge extraction data were used to determine the average excess charge carrier density ( $\Delta n$ ) of P3HT:IDTBR and P3HT:IDTBR:IDFBR (1:0.7:0.3) blends as a function of background light intensity, to allow  $V_{oc}$  to be plotted against  $\Delta n$ , as shown in Fig. 4a; these data allow the effective electronic bandgap of different blends to be compared. The approximately 90 meV shift in the  $V_{oc}$  for the P3HT:IDTBR:IDFBR device relative to P3HT:IDTBR is indicative of a larger effective bandgap for ternary blends. This can be attributed to inhibition of IDTBR aggregation in the ternary blend; where molecular aggregation typically reduces electronic and optical bandgaps, with the latter being apparent from the UV-Vis absorption data discussed above. This increased electronic bandgap for the ternary blend is likely to be the primary reason for the increased voltage output of the ternary device (Table 1)<sup>40</sup>.

The trend in  $V_{oc}$  for the P3HT:IDTBR:IDFBR blend with IDFBR fraction can further be analysed using the EQE spectra of ternary compositions. The low-energy onset of EQE in these systems is dominated by photo-generation in the acceptor, and the EQE trend therefore indicates the shift in acceptor optical gap with composition (Supplementary Fig. 7). The broadening optical gap, resulting from inhibition of aggregation in the IDTBR, will result partly from an upward shift in acceptor EA (note that the CV data presented in Fig. 1 were for a pristine, and therefore crystalline, thin film of IDTBR) and should indicate the trend in  $V_{oc}$  (refs 41–43). Figure 4b directly compares the photon energies (at EQE =  $10^{-2}\%$ ) of P3HT:IDTBR:IDFBR ternary devices and the  $V_{oc}$  as a function of IDFBR content. A clear trend is visible, with a  $\sim 80 \pm 10$  meV increase in optical gap for the 1:0.7:0.3 blend relative to the binary blend, which is in agreement with the 90 meV difference in  $V_{oc}$  between P3HT:IDTBR:IDFBR (1:0.7:0.3) and P3HT:IDTBR devices. Electroluminescence measurements, which usually probe the lowest emissive states in a blend, confirm an energetic blue shift

for P3HT:IDTBR:IDFBR devices compared to P3HT:IDTBR devices (Supplementary Fig. 7b). Note that the shift in absorption edge may not entirely account for the shift in  $V_{oc}$ , since part of the optical gap enlargement may be due to a decrease of the acceptor IP, and not only a rise in the EA, as IDTBR crystallization is suppressed. Therefore we investigate the effect of IDFBR addition on charge recombination via the charge carrier lifetime.

The carrier lifetime of P3HT:IDTBR:IDFBR (1:0.7:0.3) was measured using TPV to be  $17 \mu\text{s}$  (at 1 sun), which is two to three times longer than that measured for P3HT:IDTBR ( $6.5 \mu\text{s}$ ) (Fig. 4c). As discussed above, IDFBR exhibits a smaller EA than IDTBR, and is more miscible with P3HT, such that IDFBR is likely to accumulate in the mixed regions around the P3HT. The P3HT:IDFBR interface presents an energetic barrier to charge recombination of electrons in the (amorphous or crystalline) IDTBR with P3HT holes (that is: a three-component redox cascade). Although such a cascade is also likely to exist in the mixed phase of the binary system, the higher-lying lowest unoccupied molecular orbital (LUMO) of IDFBR compared to amorphous IDTBR will enhance the cascade effect in the ternary. This increased lifetime is likely to contribute a further 30–40 mV increase for the  $V_{oc}$  of ternary P3HT:IDTBR:IDFBR device<sup>44</sup>. A second reason for extended charge carrier lifetime in the ternary blend is the increased degree of electron trapping, evident from the SCLC measurements (Supplementary Fig. 8). The presence of traps in the binary is supported by the vitrification of the IDTBR crystallinity into an amorphous solid at a 1:0.7:0.3 ratio (Supplementary Fig. 4). In an amorphous material, a small amount of a crystalline phase will act as trap sites<sup>45</sup>. SCLC of electron-only IDTBR ( $\mu_e = 5.35 \times 10^{-4} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ ) and IDTBR:IDFBR (0.7:0.3) ( $\mu_e = 5.45 \times 10^{-4} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ ) devices<sup>46</sup> indicate a higher density of electron trap states in the 30% IDFBR blend, but otherwise very similar electron transport (Supplementary Fig. 8).

### Operational stability and energy return on investment

To be compatible with manufacturing processes, a solar cell device should be comprised of scalable materials as well as being

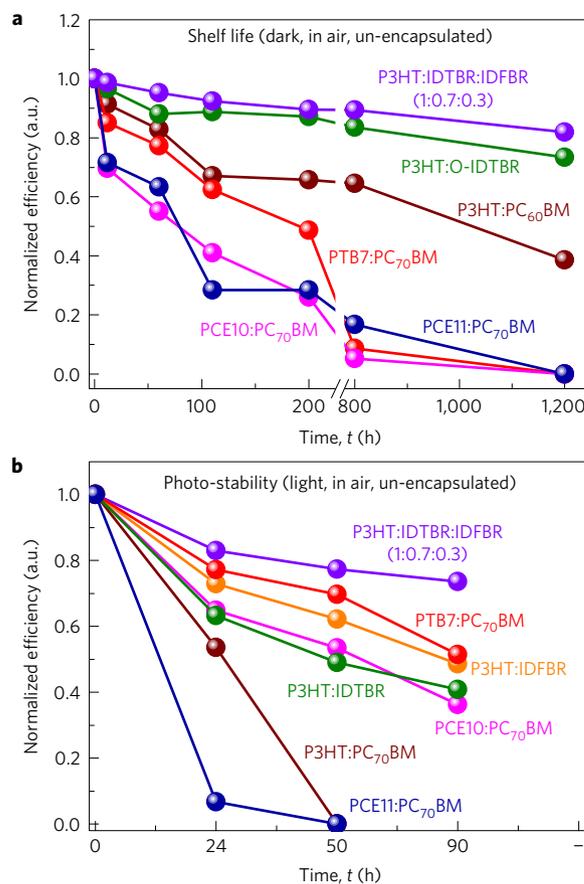
fabricated by easy processing without solvent additives, which have been shown to be detrimental to stability<sup>47</sup>. In addition, the devices need to exhibit ambient stability during fabrication as well as during operation. We tested the ambient stability of our ternary and binary devices and compared these results with a range of high-efficiency, low-bandgap polymer:fullerene solar cells, fabricated (in air) using commercially available polymers. Devices were stored at room temperature, under both dark and light (1 sun) conditions (Fig. 5). After 1,200 h in air and under dark conditions, the ternary P3HT:IDTBR:IDFBR (1:0.7:0.3) device retains 80% of its PCE (6.1%), whereas P3HT:IDTBR performance retained 70% (4.3%). However, all of the low-bandgap polymer:fullerene blends were no longer operational after only 800 h in air (Fig. 5a). In addition, we exposed high-efficiency polymer:fullerene, P3HT:NFA and P3HT:IDTBR:IDFBR devices at operating conditions (un-encapsulated, in air, AM1.5 radiation to illumination 100 mW cm<sup>-2</sup>) for an initial 90 h test (Fig. 5b). The P3HT:IDTBR:IDFBR device exhibited the best air photo-stability, retaining 85% of its initial performance after 90 h. Meanwhile, the high-efficiency PCE10:PC<sub>70</sub>BM device performance dropped to 20% of its initial value. These results suggest that the addition of IDFBR to P3HT:IDTBR blend not only improves photovoltaic performance but also has a synergistic benefit on both storage lifetime and photo-stability, which demonstrates a significant advantage for practical applications in comparison to low-bandgap:fullerene solar cells.

It is generally accepted that the main conditions for economically viable electricity generation by thin-film photovoltaics are high efficiency, low cost (represented here by ease of synthesis at the lab scale) and extended lifetime. Energy return on investment (EROI)<sup>48</sup> is a measure of the energy yield from the PV device relative to the energy invested in synthesis and manufacture. Drawing on published estimates of the embodied energy in polymer and molecule synthesis and device processing<sup>49,50</sup>, and the efficiencies of different device designs and relative stabilities demonstrated here in Fig. 5a, we estimate (see Supplementary Information for EROI) that the embodied energy of a polymer encapsulated P3HT:NFA device is at least as low as that of a similarly encapsulated, higher-efficiency polymer:PC<sub>70</sub>BM device, and that the EROI is around five times higher and is the highest of any material system studied. The increase in EROI arises in large part from the higher stability of the P3HT:NFA device shown in Fig. 5a. This suggests that a P3HT:NFA-based technology will be the most cost effective of the technologies considered in production.

In conclusion, we report highly efficient P3HT (7.7 ± 0.1%) and PCE10 (PBDT'TT-EFT) (11.0 ± 0.4%) based BHJ ternary solar cells in an inverted architecture fabricated using two non-fullerene acceptors. By optimizing the second acceptor component in a P3HT ternary blend, we have created an optimal phase morphology wherein the vitrification of the crystalline IDTBR phase by IDFBR leads to preservation of the three-phase microstructure that is favourable for photocurrent generation. This optimal phase morphology yields a higher-lying electron transport level (benefiting V<sub>oc</sub>), reduced bimolecular recombination and a preserved collection efficiency, resulting in a simultaneous improvement in V<sub>oc</sub>, J<sub>sc</sub> and FF for P3HT:IDTBR:IDFBR devices. The PCE10 preliminary results also show that two-NFA ternary approach can further boost the PCE of high-efficiency potential polymers. This demonstration revives the use of P3HT in high-performance OPV devices, closing the gap between the efficiency, lifetime, energy efficiency and cost requirements needed to commercialize OPV.

## Methods

Methods and any associated references are available in the [online version of the paper](#).



**Figure 5 | Storage lifetime and photo-stability of P3HT:IDTBR:IDFBR and high-efficiency, low-bandgap polymer:fullerene devices.** **a**, Shelf storage lifetime (dark, in air) comparison of P3HT:IDTBR:IDFBR device efficiencies with other polymer:fullerene systems. Devices were exposed to ambient conditions over a 1,200 h duration or until high devices no longer showed any diode behaviour. **b**, Photo-stability of P3HT:IDTBR:IDFBR device and polymer:fullerene solar cells (in air, un-encapsulated, under AM1.5 illumination at 1 sun) for 90 h.

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## Author contributions

D.B. and R.S.A. prepared the manuscript. S.H. and A.W. synthesized the non-fullerene acceptors. R.S.A. fabricated and characterized solar cell devices. D.B. and N.G. carried out CE and TPV measurements. M.A. performed the *in situ* GIWAXS and UV-Vis absorption measurements during spin coating. D.A.H. performed static GIWAXS measurements. J.A.R. did the SCLC measurements. S.L. performed the DSC measurements. R.S.A. and M.N. performed stability measurements. C.J.M.E. helped J.N. with EROI modelling. All authors discussed the results and commented on the manuscript. C.J.B. supervised charge extraction measurements. J.R.D. supervised TPV measurements, A.A. supervised *in situ* GIWAXS and UV-Vis measurements, A.S. supervised static GIWAXS measurements, T.K. and J.N. supervised SCLC, electroluminescence and EQE measurements. I.M. revised the manuscript and supervised and directed the project.

## Additional information

Supplementary information is available in the online version of the paper. Reprints and permissions information is available online at [www.nature.com/reprints](http://www.nature.com/reprints). Correspondence and requests for materials should be addressed to D.B., R.S.A. or I.M.

## Competing financial interests

The authors declare no competing financial interests.

## Methods

All materials are purchased from Sigma Aldrich except 60PCBM from Solenne. PCE10 is supplied from CalOS Organic semiconductors.

**Characterization.**  $^1\text{H}$  and  $^{13}\text{C}$  nuclear magnetic resonance (NMR) spectra were collected on a Bruker AV-400 spectrometer at 298 K and are reported in ppm relative to tetramethylsilane (TMS). UV-Vis absorption spectra were recorded on a UV-1601 Shimadzu UV-Vis spectrometer. Differential scanning calorimetry (DSC) experiments were carried out with a Mettler Toledo DSC822 instrument at a heating rate of  $5^\circ\text{C min}^{-1}$  under nitrogen. Samples were prepared by drop-casting the materials from  $\text{CHCl}_3$  solution directly into the DSC pan and allowing the solvent to evaporate under Ar. GIWAXS was done at beamline 7.3.3 Lawrence Berkeley National Lab (LBNL). The sample was secured inside a helium chamber, with  $\text{O}_2$  levels below 1%. The X-ray wavelength was 1.24 Å (10 keV), and the sample was irradiated at a fixed incidence angle of  $0.125^\circ$ . The scattering patterns were recorded using a Pilatus 2M detector at a fixed distance of 287.377 mm. Two-dimensional data reduction was analysed using the Nika 2D software package and peak information was accessed by Gaussian fitting. Samples for GIWAXS were spin coated on Si (100) substrates following the same spin coating and annealing procedures as were used in fabricating solar cells.

### *In situ* grazing incidence wide angle X-ray scattering measurements (GIWAXS).

*In situ* experiments were performed using a set-up described in previous work<sup>35,36</sup> at beamline D1 at the Cornell High Energy Synchrotron Source, Wilson Lab, New York, USA. The scattering pattern during the spin coating process was recorded using a fast 2D detector (PILATUS 200 k from Dectris) with an exposure time of 0.18 s. The wavelength of the incident X-ray beam was 1.1555 Å. The sample-to-detector-distance was set to 173.756 mm. The incidence angle of the X-ray beam with respect to the sample plane was  $0.17^\circ$ . Calibration of the lengths in reciprocal space was done by using silver behenate.

***In situ* UV-Vis absorption measurements during spin coating.** *In situ* UV-Vis absorption measurements were performed using a set-up described previously<sup>37</sup>. An integration time of 0.2 s per absorption spectrum was used to collect the transmission measurements. The equation [ $A_\lambda = -\log_{10}(T)$ ] was used to calculate the UV-Vis absorption spectra from the transmission spectra, where  $A_\lambda$  is the absorbance at a certain wavelength ( $\lambda$ ) and  $T$  is the transmitted radiation.

**OPV devices.** The photovoltaic performance of the binary and ternary blend solar cells was measured with a device architecture comprising of: indium tin oxide (ITO)/zinc oxide (ZnO)/active layer ( $85 \pm 5$  nm)/molybdenum oxide ( $\text{MoO}_3$ )/Ag, where the active layer consists of either D:A<sub>1</sub> or D:A<sub>1</sub>:A<sub>2</sub>. Glass substrates were used with pre-patterned ITO. These were cleaned by sonication in detergent, deionized water, acetone and isopropanol, followed by oxygen plasma treatment. ZnO layers were deposited by spin coating a zinc acetate dihydrate precursor solution (60  $\mu\text{l}$  monoethanolamine in 2 ml 2-methoxyethanol) followed by annealing at  $150^\circ\text{C}$  for 10–15 min, giving layers of 30 nm. The active layers were deposited from 20 mg ml<sup>-1</sup> solutions in chlorobenzene by spin coating at 2,000 r.p.m., followed by annealing at  $130^\circ\text{C}$  for 10 min for P3HT blends and without annealing for PCE10 blend. Active layer thicknesses were  $\sim 90$  nm (averaged over 10 devices) for both acceptor blends.  $\text{MoO}_3$  (10 nm) and Ag

(100 nm) layers were deposited by evaporation through a shadow mask, yielding active areas of  $0.045\text{ cm}^2$  in each device. For device optimization, the ratio of A<sub>2</sub> is varied with respect to A<sub>1</sub> such that the donor:acceptor (D:A) mass ratio is fixed at 1:1. All ternary devices were processed using chlorobenzene without further processing or solvent additives, and active layers were pre-annealed in inert atmosphere at  $130^\circ\text{C}$  for 10 min, which is required for P3HT crystallization<sup>9</sup>. Current density–voltage ( $J$ – $V$ ) characteristics were measured in both forward and backward directions (no difference observed) at room temperature, with 20 mA s<sup>-1</sup> scan speed in air, using a xenon lamp at AM1.5 solar illumination (Oriel Instruments) calibrated to a silicon reference cell with a Keithley 2400 source meter, correcting for spectral mismatch (active area  $0.045\text{ cm}^2$  using a mask). Efficiencies are reported averaging 12 photovoltaic devices. Incident photon conversion efficiency (IPCE) was measured by a 100 W tungsten halogen lamp (Bentham IL1 with Bentham 605 stabilized current power supply) coupled to a monochromator with computer controlled stepper motor. The photon flux of light incident on the samples was calibrated using an ultraviolet-enhanced silicon photodiode. A 590 nm long-pass glass filter was inserted into the beam at illumination wavelengths longer than 580 nm to remove light from second-order diffraction. Measurement duration for a given wavelength was sufficient to ensure the current had stabilized.

**$J$ – $V$  measurements for storage and operational stability.** The same inverted architecture solar cell devices used for  $J$ – $V$  and EQE measurements were then taken to the storage and operational stability measurements. For storage stability, the inverted architecture devices were left in ambient cleanroom conditions ( $\sim 20^\circ\text{C}$ ,  $<40\%$  humidity) in dark conditions between each measurement. Data are taken with intervals and solar cell devices were exposed to  $100\text{ mW cm}^{-2}$  illumination for light measurements. For operational stability measurement, devices were transferred to same ambient cleanroom conditions to expose them to air, then  $J$ – $V$  measurements were performed under constant  $100\text{ mW cm}^{-2}$  illumination for 90 h.

**TPV and CE measurements.** A 405 nm laser diode was used to ensure the solar cells were approximately in the  $V_{oc}$  condition. Driving the laser intensity with a waveform generator (Agilent 33500B) and measuring the light intensity with a highly linear photodiode allowed us to reproducibly adjust the light intensity with an error below 0.5% over a range of 0.2 to 4 suns. A small perturbation was induced with a second 405 nm laser diode driven by a function generator from Agilent. The intensity of the short (50 ns) laser pulse was adjusted to keep the voltage perturbation below 10 mV, typically at 5 mV. After the pulse, the voltage decays back to its steady-state value in a single exponential decay. The characteristic decay time was determined from a linear fit to a logarithmic plot of the voltage transient, and returned the small perturbation charge carrier lifetime. In charge extraction measurements, a 405 nm laser diode illuminated the solar cell for 200  $\mu\text{s}$ , which was sufficient to reach a constant open-circuit voltage with steady-state conditions. At the end of the illumination period, an analog switch was triggered that switched the solar cell from open-circuit to short-circuit ( $50\ \Omega$ ) conditions within less than 50 ns.

**Space-charge-limited current (SCLC).** SCLC measurements were performed on electron-only devices of the structure ITO/TiO<sub>2</sub>/P3HT:acceptor/Ca/Al. The current–voltage characteristics were fitted using a drift–diffusion solver.